

No. of Printed Pages : 4

Roll No.

120933/30933

3rd Sem. / Electrical / PE

Subject : Electronics - I / Basic Electronics

Time : 3 Hrs.

M.M. : 100

SECTION-A

Note:Very Short Answer type questions. Attempt any 15 parts. (15x2=30)

- Q.1
- a) Define function capacitance of a diode.
 - b) Define a constant voltage and current source.
 - c) What are N-type semiconductors.
 - d) What is forward biasing.
 - e) Define Input impedance.
 - f) Symbol of P channel JFET.
 - g) What is photodiode.
 - h) What is operating point.
 - i) Define Rectifier Efficiency of Half wave rectifier.

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- j) Define MOSFET.
- k) What are different types of coupling used in amplifier.
- l) Draw symbol of PNP transistor.
- m) Give graphical representation of current source.
- n) What is varacter diode.
- o) Define Decibel gain and current gain.
- p) Applications of transformer coupled amplifiers.
- q) Define depletion layer.
- r) Define diffusion current.

SECTION-B

Note:Short answer type questions. Attempt any ten parts 10x4=40

- Q.2
- i) Give the concept of AC load line.
 - ii) Draw the symbol of NPN and its working.
 - iii) How zener diode stabilises voltage.

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- iv) How operating pointing is changed due to temperature.
- v) Draw the frequency response of single stage transistor amplifier.
- vi) Draw V-I characteristic of PN junction diode.
- vii) Compare intrinsic semiconductor and extrinsic semiconductor.
- viii) What are H-parameters, why they are used.
- ix) What are active and passive components. Give examples of each.
- x) Give the characteristics of MOSFET.
- xi) Explain forward and reverse biasing of diode.
- xii) What is loading effect in multistage amplifiers.
- xiii) Explain collector to base bias circuit.
- xiv) Write the comparison between BJT and JFET.
- xv) Explain the working of half wave rectifier circuit.

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SECTION-C

Note: Long answer type questions. Attempt any three questions. 3x10=30

- Q.3 Explain various types of filter circuits used and their applications.
- Q.4 Differentiate semiconductor, conductor and insulators on the basis of energy band structure. Why semiconductors have -ve temperature coefficient of resistance.
- Q.5 Draw the input and output characteristics of transistor in CE configuration. and explain.
- Q.6 Explain the need of multistage amplifiers and working of Transformer coupled amplifiers and its frequency response.
- Q.7 (i) Single Stage Transistor Amplifier circuit in CE configuration.
(ii) JFET as an amplifier.

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